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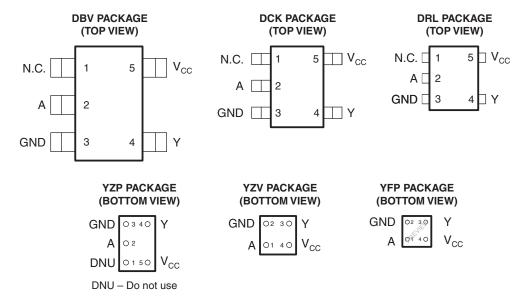
Jameco Part Number 1044620



FEATURES

- Available in the Texas Instruments
 NanoFree[™] Package
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{nd} of 3.5 ns at 3.3 V
- Low Power Consumption, 1-μA Max I_{cc}

- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions. N.C. – No internal connection

DESCRIPTION/ORDERING INFORMATION

This single buffer gate is designed for 1.65-V to 5.5-V V_{CC} operation. The SN74LVC1G34 performs the Boolean function Y = A in positive logic.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

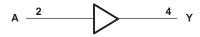
T _A	PACKAGE ⁽¹⁾	PACKAGE ⁽¹⁾		TOP-SIDE MARKING ⁽²⁾
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74LVC1G34YFPR	- C9
	NanoFree™- WCSP (DSBGA) 0.23-mm Large Bump - YZP	Reel of 3000	SN74LVC1G34YZPR	09_
−40°C to 85°C	NanoFree [™] – WCSP (DSBGA) 0.23-mm Large Bump – YZV (Pb-free)	Reel of 3000	SN74LVC1G34YZVR	
	SOT (SOT-23) –DBV	Reel of 3000	SN74LVC1G34DBVR	- C34
	301 (301-23) –DBV	Reel of 250	SN74LVC1G34DBVT	C34_
	SOT (SC-70) – DCK	Reel of 3000	SN74LVC1G34DCKR	
	301 (30-70) - DOK	Reel of 250	SN74LVC1G34DCKT	C9_
	SOT (SOT-553) - DRL	Reel of 4000	SN74LVC1G34DRLR	

- (1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (2) DBV/DCK/DRL: The actual top-side marking has one additional character that designates the assembly/test site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free). YZV: The actual top-side marking is on two lines. Line 1 has four characters to denote year, month, day, and assembly/test site. Line 2 has two characters which show the family and function code. Pin 1 identifier indicates solder-bump composition (1 = SnPb, = Pb-free).

FUNCTION TABLE

INPUT A	OUTPUT Y
Н	Н
L	L

LOGIC DIAGRAM (POSITIVE LOGIC) (DBV, DCK, DRL, YFP, and YZP Package)



LOGIC DIAGRAM (POSITIVE LOGIC) (YZV Package)





Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range		-0.5	6.5	V
Vo	Voltage range applied to any output in the h	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾		6.5	V
Vo	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current		±50	mA	
	Continuous current through V _{CC} or GND			±100	mA
		DBV package		206	
		DCK package		252	
θ_{JA}	Package thermal impedance (4)	DRL package		142	°C/W
		YFP/YZP package		132	
		YZV package		116	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V	Cumply valtage	Operating	1.65	5.5	V	
V_{CC}	Supply voltage	Data retention only	1.5	1.5		
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
V	Lligh lovel input veltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
V_{IH}	High-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		V	
		V _{CC} = 4.5 V to 5.5 V	$0.7 \times V_{CC}$			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
V	Low lovel input veltage	V _{CC} = 2.3 V to 2.7 V		0.7	V	
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8	V	
		V _{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V_{CC}	V	
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V		-8		
I_{OH}	High-level output current	V 2V	-16 -24		mA	
		V _{CC} = 3 V				
		V _{CC} = 4.5 V		-32		
		V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8		
I_{OL}	Low-level output current	V 0.V		16	mA	
		V _{CC} = 3 V		24		
		V _{CC} = 4.5 V		32		
		V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20		
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		10		
T _A	Operating free-air temperature	,	-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP	(1) MAX	UNIT
	$I_{OH} = -100 \mu A$	1.65 V to 5.5 V	V _{CC} - 0.1		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
V	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		V
V _{OH}	$I_{OH} = -16 \text{ mA}$	3 V	2.4		V
	$I_{OH} = -24 \text{ mA}$	3 V	2.3		
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8		
	I _{OL} = 100 μA	1.65 V to 5.5 V		0.1	
	I _{OL} = 4 mA	1.65 V		0.45	
V	$I_{OL} = 8 \text{ mA}$	2.3 V		0.3	V
V _{OL}	I _{OL} = 16 mA	3 V		0.4	V
	I _{OL} = 24 mA	3 V		0.55	
	I _{OL} = 32 mA	4.5 V		0.55	
l _l	V _I = 5.5 V or GND	0 to 5.5 V		±1	μΑ
I _{off}	V_I or $V_O = 5.5 \text{ V}$	0		±10	μΑ
I _{cc}	$V_I = 5.5 \text{ V or GND}$ $I_O = 0$	1.65 V to 5.5 V		1	μΑ
Δl _{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	3 V to 5.5 V		500	μΑ
C _i	$V_I = V_{CC}$ or GND	3.3 V	3	.5	pF

⁽¹⁾ All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.	V _{CC} = 1.8 V ± 0.15 V		V_{CC} = 2.5 V \pm 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V	
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Υ	2	9.9	1.5	6	1	3.5	1	2.9	ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.	1.8 V 15 V		$C = 2.5 \text{ V}$ $V_{CC} = 3.3 \text{ V}$ $V_{CC} = 5 \text{ V}$ $\pm 0.2 \text{ V}$ $\pm 0.3 \text{ V}$ $\pm 0.5 \text{ V}$			UNIT		
	(INFOT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	3.2	8.6	1.5	4.4	1.5	4.1	1	3.2	ns

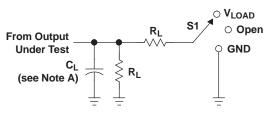
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	16	16	16	18	pF



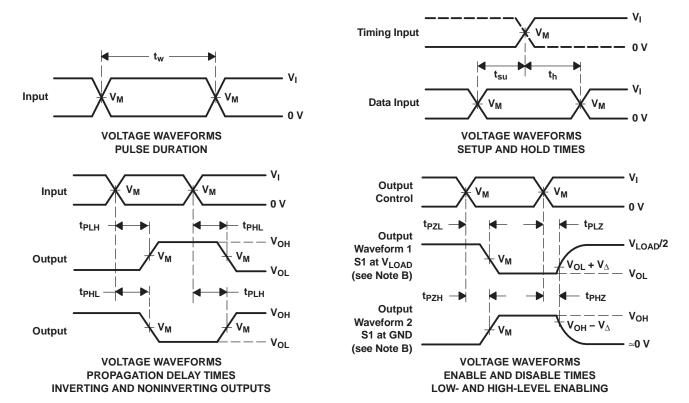
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

V	INF	INPUTS		V			V
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_{Δ}
1.8 V \pm 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 M Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	2×V _{CC}	15 pF	1 M Ω	0.3 V



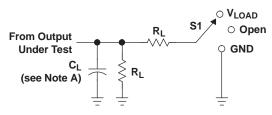
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



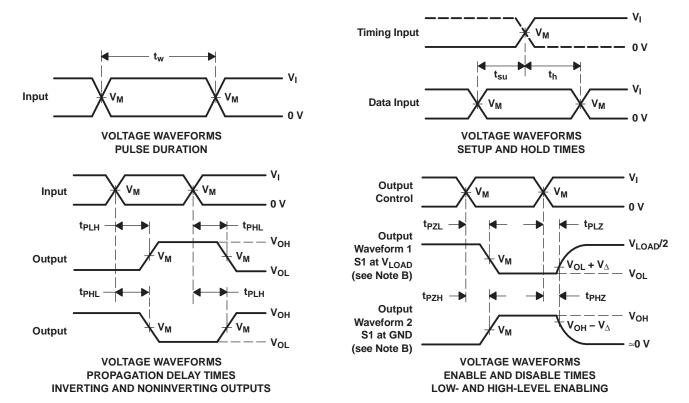
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

V	INF	PUTS	V V				V
V _{CC}	VI	t _r /t _f	V _M	V _{LOAD}	CL	R _L	$V_{\!\scriptscriptstyle \Delta}$
1.8 V ± 0.15 V	V _{CC}	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	2×V _{CC}	50 pF	500 Ω	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVC1G34DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DRLR	ACTIVE	SOT-553	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34DRLRG4	ACTIVE	SOT-553	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G34YZPR	ACTIVE	WCSP	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74LVC1G34YZTR	ACTIVE	DSBGA	YZT	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74LVC1G34YZVR	ACTIVE	DSBGA	YZV	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

29-May-2007

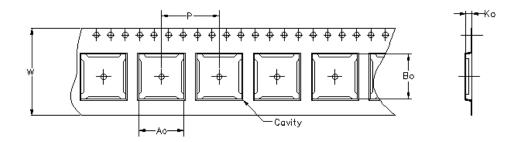
retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.
Bo =	Dímension	designed	to	accommodate	the	component	length.
Ko =	Dímension	designed	to	accommodate	the	component	thickness.
W = Overall width of the carrier tape.							
P = Pitch between successive cavity centers.							



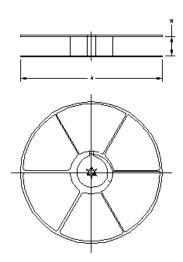
TAPE AND REEL INFORMATION





3-Sep-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G34DBVR	DBV	5	HNT	180	9	3.23	3.17	1.37	4	8	Q3
SN74LVC1G34DBVT	DBV	5	HNT	180	9	3.23	3.17	1.37	4	8	Q3
SN74LVC1G34DCKR	DCK	5	HNT	180	9	2.24	2.34	1.22	4	8	Q3
SN74LVC1G34DCKT	DCK	5	HNT	180	9	2.24	2.34	1.22	4	8	Q3
SN74LVC1G34DRLR	DRL	5	HNT	180	9	1.78	1.78	0.69	4	8	Q3
SN74LVC1G34YZPR	YZP	5	ASEK	180	8	1.02	1.52	0.66	4	8	Q1
SN74LVC1G34YZTR	YZT	4	ASEK	180	8	1.05	1.05	0.7	4	8	Q1
SN74LVC1G34YZVR	YZV	4	ASEK	180	8	1.02	1.02	0.56	4	8	Q1

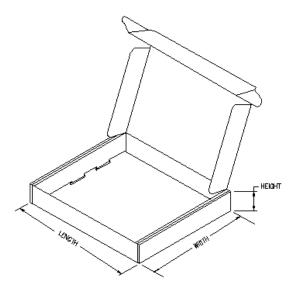


TAPE AND REEL BOX INFORMATION

Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G34DBVR	DBV	5	HNT	202.0	201.0	28.0
SN74LVC1G34DBVT	DBV	5	HNT	202.0	201.0	28.0
SN74LVC1G34DCKR	DCK	5	HNT	202.0	201.0	28.0
SN74LVC1G34DCKT	DCK	5	HNT	202.0	201.0	28.0
SN74LVC1G34DRLR	DRL	5	HNT	202.0	201.0	28.0
SN74LVC1G34YZPR	YZP	5	ASEK	220.0	220.0	34.0
SN74LVC1G34YZTR	YZT	4	ASEK	220.0	220.0	34.0
SN74LVC1G34YZVR	YZV	4	ASEK	220.0	220.0	34.0



3-Sep-2007



DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

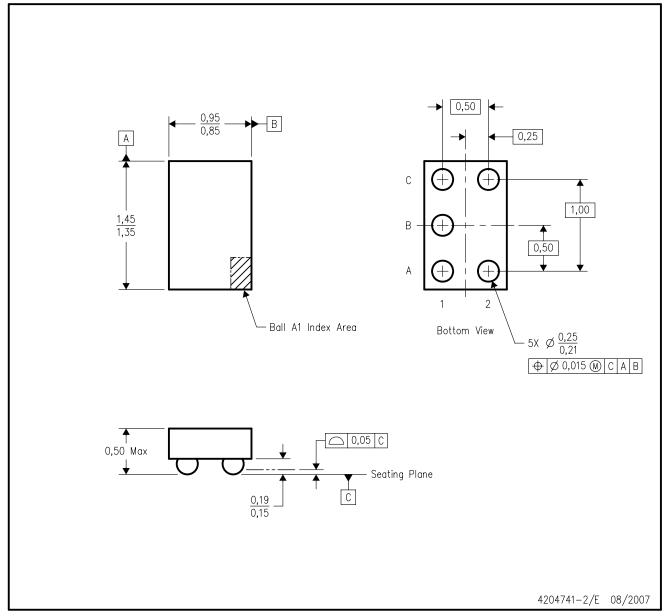
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs.

 Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.
- D. JEDEC package registration is pending.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



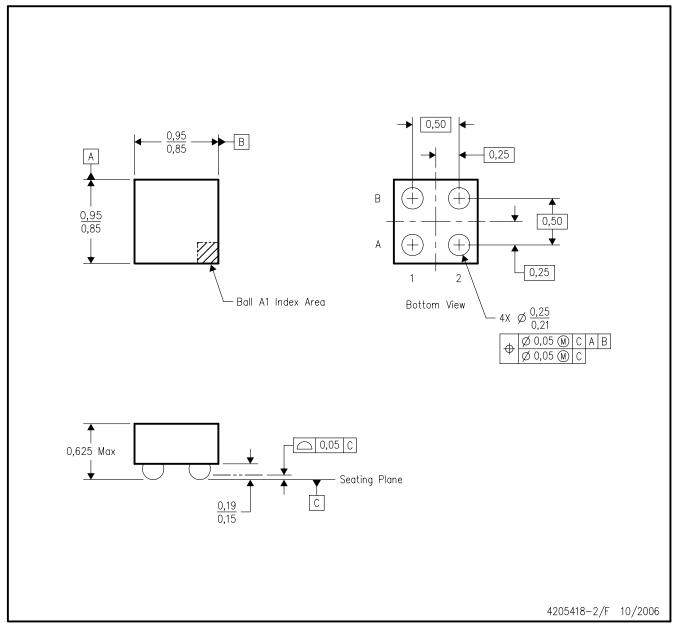
NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).



YZT (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



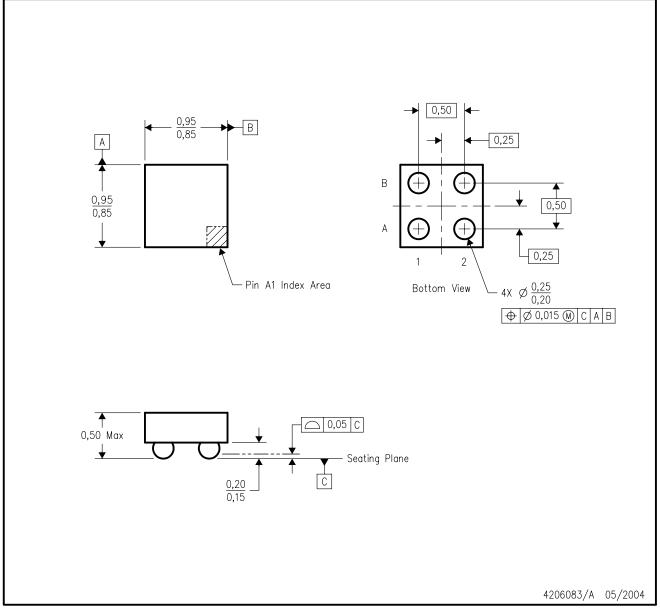
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is Lead-free. Refer to the 4 YET package (drawing 4205421) for tin-lead (SnPb).



YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



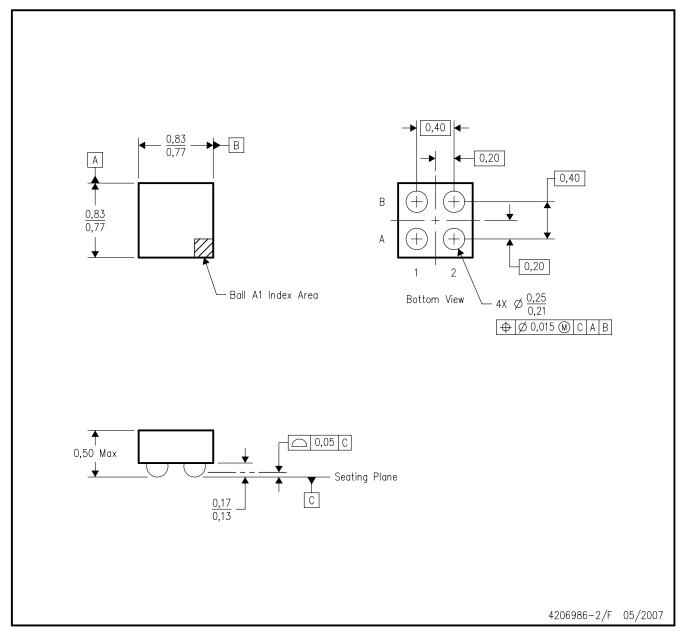
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoFree $^{\text{TM}}$ package configuration.
- D. This package contains lead—free balls. Refer to the 4 YEV package (drawing 4206082) for tin—lead (SnPb) balls.



YFP (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This is a lead free solder ball design.



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